NTP85N08, NTB85N08, NTP85N08L, NTB85N08L

Product Preview 80 V Power MOSFET

ON Semiconductor utilizes its latest MOSFET technology process to manufacture 80 V power MOSFET devices to achieve the lowest possible on-resistance per silicon area. These 80 V devices are designed for Power Management solutions in 42 V Automotive system applications. Typical applications include integrated starter alternator, electronic power steering, electronic fuel injection, catalytic converter heaters and other high power applications made possible via an automotive 42 V bus. ON Semiconductor's latest technology offering continues to offer high avalanche energy capability and low reverse recovery losses.

ELECTRICAL CHARACTERISTICS

 $(T_J = 25^{\circ}C \text{ unless otherwise noted})$

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain–to–Source Breakdown Voltage (V _{GS} = 0 Vdc, I _D = 250 μAdc)	V _(BR) DSS	80	_	_	Vdc	
Zero Gate Voltage Drain Current ($V_{DS} = 80 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}$) ($V_{DS} = 80 \text{ Vdc}, V_{GS} = 0 \text{ Vdc},$ $T_J = 150^{\circ}\text{C}$)	IDSS			1.0 10	μAdc	
Gate–Body Leakage Current (V _{GS} = ±20 Vdc, V _{DS} = 0 Vdc)	IGSS	_	-	±100	nAdc	

ON CHARACTERISTICS

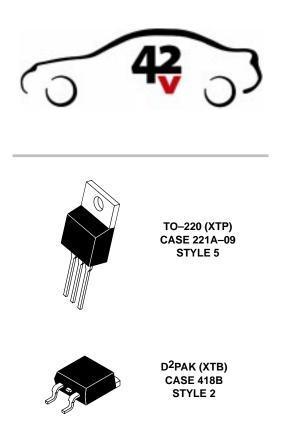
Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 250 μAdc) NTP/B85N08 NTP/B85N08L	VGS(th)	2.0 1.0	3.0 1.5	4.0 2.0	Vdc
Static Drain-to-Source On-Resistance (I _D = 42.5 Adc) NTP/B85N08, V _{GS} = 10 V NTP/B85N08L, V _{GS} = 5 V	R _{DS(on)}		13 15	-	mΩ



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85 AMPERES 85N08 Typ RDS(on) = 13 mΩ 85N08L Typ RDS(on) = 15 mΩ

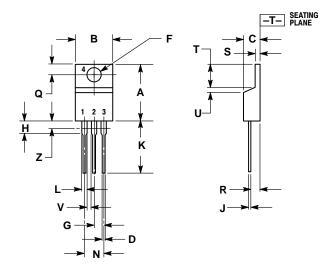


This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

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PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AA**



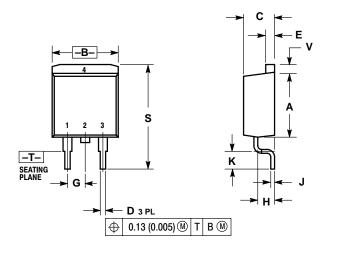
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.018	0.025	0.46	0.64	
Κ	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
Ν	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
V	0.045		1.15		
Ζ		0.080		2.04	

STYLE 5: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN

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D²PAK CASE 418B-03 ISSUE D



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.340	0.380	8.64	9.65	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.83	
D	0.020	0.035	0.51	0.89	
E	0.045	0.055	1.14	1.40	
G	0.100 BSC		2.54 BSC		
Н	0.080	0.110	2.03	2.79	
J	0.018	0.025	0.46	0.64	
K	0.090	0.110	2.29	2.79	
S	0.575	0.625	14.60	15.88	
V	0.045	0.055	1.14	1.40	

STYLE 2: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN

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